

2ST501T

2ST501T Information



For Reference Only

Part Number	2ST501T
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 350V 4A TO-220
Package	TO-220-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

Part



2ST501T Specifications

	20775017
Manufacturer Part Number	2ST501T
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	4A
Voltage - Collector Emitter Breakdown (Max)	350V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 2mA, 2A
Current - Collector Cutoff (Max)	100µА
DC Current Gain (hFE) (Min) @ Ic, Vce	2000 @ 2A, 2V
Power - Max	100W
Frequency - Transition	-
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

2ST501T Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about 2ST501T, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com